1	Supplemental Material: Localized Excitons in Defective Monolayer Germanium
2	Selenide
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12 I. DEFECT STATE IDENTIFICATION

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¹³ $\epsilon_{d,corr}$ is applied to defect-centered bands identified by ¹⁴ their spatial extent. For each band, the spatial extent of ¹⁵ the orbital is calculated for the orbital density at the Γ ¹⁶ point and an average of the orbitals at all k-points. The ¹⁷ spatial extent $\langle \mathbf{r} \rangle$ is calculated as

$$\langle \mathbf{r} \rangle = \frac{\int |\mathbf{r} - \mathbf{r}_{\mathbf{d}}| \rho(\mathbf{r}) dr^3}{\int \rho(\mathbf{r}) dr^3},\tag{1}$$

 $_{18}$ where $\mathbf{r_d}$ is the center of mass of the electron density.

Table I presents the calculated $\langle \mathbf{r} \rangle$ for near-gap states. 19 The orbitals associated with these states appear in Fig-20 ure 3 in the main text. The three states identified as 21 defect-centered are labeled as "Defect 1", "Defect 2", and 22 "Defect 3". The pristine-like states (such as the valence 23 ²⁴ band (VB)) have an average extent of ~ 8 Å, at $\mathbf{k} = \Gamma$ $_{25}$ and a bandwidth of ~ 0.3 eV. With the introduction of the defect, states identified as defect-like show a reduced 26 extent and a reduced bandwidth. This is best illustrated 27 for Defect 3, with extent of only ~ 4 Å both when only 28 the orbital at $\mathbf{k} = \Gamma$ is considered and when orbitals are 29 ³⁰ averaged over all k-points. Defect 1 and Defect 3 both ³¹ have very low bandwidths, of less than 0.1 Å. The extent 32 of Defect 1, Defect 2, CB and CB +1 are more ambiguous in that the orbital extent at Γ is different than when 33 the orbitals are averaged over all k. We choose the states 34 ³⁵ identified as Defects 1 and 2 due to the localization for ³⁶ the orbital at Γ .

TABLE I.	Calculated	orbital	spatial	extent	$\langle \mathbf{r} \rangle$	\mathbf{as}	defined	by
Equation 1	l for near-ga	ap state	es					

	VB	Defect 1	Defect 2	Defect 3	CB	CB + 1
$\mathbf{k} = \Gamma (\mathbf{A})$	8.1	5.0	7.0	4.2	8.1	8.2
All \mathbf{k} (Å)	8.3	6.8	6.5	3.9	6.1	6.8
Bandwidth (eV)	0.33	0.08	0.23	0.08	0.34	0.27

II. ELECTRON-HOLE CORRELATION ENVELOPE FUNCTION FOR DELOCALIZED PRISTINE-LIKE TRANSITIONS

Figures 1 and 2 show the ECF (calculated according
to Equation 2 in the main text) for the lowest energy
Wannier-Mott exciton in the pristine monolayer GeSe
and the second excited state for the defective monolayer
GeSe, respectively.



FIG. 1. a) Two-dimensional ECF for pristine monolayer GeSe top view and side view. b) Radial ECF calculated in the a-b plane.



FIG. 2. a) Two-dimensional ECF for the second energy transition in with defect GeSe top view and side view. b) Radial ECF calculated in the a-b plane.